



INVENTEK SYSTEMS

ISM4334X-L77 Embedded SiP Module 802.11 a/b/g/n Bluetooth 4.0 & NFC Data Sheet





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1 PART NUMBER DETAIL DESCRIPTION

1.1 Ordering Information

Device	Description	Ordering Number
ISM43341-L77	2.4/5G Wi-Fi, Bluetooth, NFC SiP Module	ISM43341-L77
ISM43340-L77	2.4/5G Wi-Fi, Bluetooth SiP Module	ISM43340-L77
ISM43341-SDIO- EVB or ISM43340	SDIO Evaluation Board	ISM43341-SDIO-EVB

2 OVERVIEW

The Inventek ISM4443X single-chip quad-radio device provides the highest level of integration for a wireless system, with integrated dual band (2.4 GHz/ 5 GHz) IEEE 802.11 a/b/g and single-stream IEEE 802.11n MAC/baseband/radio, Bluetooth 4.0. The ISM43341 also integrates a low power NFC controller. The ISM4443X includes integrated power amplifiers, LNAs and T/R switches for the 2.4 GHz and 5 GHz WLAN bands, greatly reducing the external part count, PCB footprint, and cost of the solution.

It provides a small form-factor solution with minimal external components to drive down cost for mass volumes and allows for handheld device flexibility in size, form and function. Comprehensive power management circuitry and software ensure the system can meet the needs of high mobile devices that require minimal power consumption and reliable operations.

The ISM4443X is compatible with the Bluetooth Low Energy operating mode, which provides a dramatic reduction in the power consumption of the Bluetooth radio and baseband. The primary application for this mode is to provide support for low data rate devices, such as sensors and remote controls.

The ISM4443X implements the highly sophisticated Enhanced Collaborative Coexistence algorithms and hardware mechanisms, allowing for an extremely collaborative Bluetooth coexistence scheme along with coexistence support for external radios such as cellular and LTE, GPS, and Ultra-Wideband. For the WLAN section, host interface is a SDIO v2.0 interface. An independent, high-speed UART is provided for the Bluetooth host interface. Separate independent interfaces (I²C-compatible, SPI and UART) for NFC are also provided.



3 FEATURES

The ISM4443X supports the following WLAN, Bluetooth functions:

- Dual-band 2.4 GHz and 5 GHz IEEE 802.11 a/b/g/n
- Single-stream IEEE 802.11n support for 20 MHz and 40 MHz channels provides PHY layer rates up to 150 Mbps for typical upper-layer throughput in excess of 90 Mbps.
- Supports a single 2.4 GHz antenna shared between WLAN and Bluetooth
- IEEE 802.11a/b/g/n dual-band radio with internal Power Amplifiers, LNAs and T/R switches
- OneDriver™ software architecture for easy migration from existing embedded WLAN and Bluetooth devices as well as future devices.
- Bluetooth v4.0 with integrated Class 1 PA
- Concurrent Bluetooth, NFC and WLAN operation
- On-chip WLAN driver execution capable of supporting IEEE 802.11 functionality
- Single and dual-antenna support
- WLAN host interface :
 - o SDIO v2.0, including default and high-speed timing.
- BT host digital interface (can be used concurrently with above interface):
 - UART (up to 4 Mbps)
- ECI enhanced coexistence support, ability to coordinate BT SCO transmissions around WLAN receives
- I²S/PCM for BT audio
- HCI high-speed UART (H4, H4 +, H5) transport support
- Bluetooth SmartAudio® technology improves voice and music quality to headsets
- Bluetooth low power inquiry and page scan
- Bluetooth Low Energy (BLE) support
- Bluetooth Packet Loss Concealment (PLC)
- Bluetooth Wide Band Speech (WBS)

The BBC supports all Bluetooth 4.0 features, with the following benefits:

- Dual-mode classic Bluetooth and classic Low Energy (BT and BLE) operation.
- Low Energy Physical Layer
- Low Energy Link Layer
- Enhancements to HCI for Low Energy
- Low Energy Direct Test mode
- AES encryption

The ISM43341 supports the following NFC features:

- Support for the ISO/IEC 18092, ISO/IEC 21481, ISO/IEC 14443 Types A, B and B', Japanese Industrial Standard (JIS) (X) 6319-4 and ISO/IEC 15693 standards
- No active components required for antenna or field-power conditioning
- Individual byte framing



- Hardware-based collision detection and modulation controls
- Reader/Writer (R/W) mode
- Active and Passive Peer-to-Peer (P2P) mode
- Tag/Card Emulation mode:
 - Support for battery-enabled card emulation mode
 - o Support for two levels of "residual" battery-assisted card emulation mode
 - Support for "battery-off" card emulation mode (completely powered from the field)
- Dual Signal Wire Protocol (SWP) interfaces:
 - SWP_0 with platform power management unit (PMU) power switching to a UICC SIM card
 - SWP_1 for embedded secure element or a second UICC SIM card
- Supports Application ID (AID) routing between a reader and secure element(s)
- Ability to recover card emulation personality data
- Internal low-power oscillator for periodic wake-up and mode switch operation
- Low-Power Target Detection mode for extremely low average current consumption ("sniff mode")
- NFC Forum NFC Controller Interface (NCI) for the host interface

3.1 Limitations

Inventek Systems products are not authorized for use in safety-critical applications (such as life support) where a failure of the Inventek Systems product would reasonably be expected to cause severe personal injury or death.

4 COMPLEMENTARY DOCUMENTATION

4.1 Inventek Systems

- Evaluation Board
 - SDIO Evaluation Board Specification
 - EVB User's Guide
 - Drivers under NDA
 - o Design Guidelines



5 BLOCK DIAGRAM



Figure 1 Inventek's ISM4443X General Block Diagram (NFC on ISM43341 version only)

6 HOST INTERFACES

6.1 UART Interface

The ISM4443X shares a single UART for Bluetooth. The UART is a standard 4-wire interface (RX, TX, RTS and CTS) with adjustable baud rates from 9600 bps to 4.0 Mbps. The interface features an automatic baud rate detection capability that returns a baud rate selection. Alternatively, the baud rate may be selected through a vendor-specific UART HCI command.

The UART has a 1040-byte receive FIFO and a 1040-byte transmit FIFO to support EDR. Access to the FIFO is conducted through the AHB interface through either DMA or the CPU. The UART supports the Bluetooth 4.0 UART HCI specification: H4, a custom Extended H4 and H5. The default baud rate is 115.2 Kbaud.

The UART supports the 3-wire H5 UART transport, as described in the Bluetooth specification ("Three-wire UART Transport Layer"). Compared to H4, the H5 UART transport reduces the number of signal lines required by eliminating the CTS and RTS signals.

The ISM4443X UART can perform XON/XOFF flow control and includes hardware support for the Serial Line input Protocol (SLIP). It can also perform wake-on activity. For example, activity on the RX or CTS inputs can wake the chip from a sleet state.



ISM4334x Product Specification

Normally, the UART baud rate is set by a configuration record downloaded after device reset, or by automatic baud rate detection, and the host does not need to adjust the baud rate. Support for changing the baud rate during normal HCI UART operation is included through a vendor-specific command that allows the host to adjust the contents of the baud rate registers. The ISM4443X UARTs operate correctly with the host UART as long as the combined baud rate error of the two devices is within $\pm 2\%$ (see Table 12).

Desired Rate	Actual Rate	Error (%)
400000	400000	0.00
3692000	3692308	0.01
300000	300000	0.00
2000000	2000000	0.00
1500000	1500000	0.00
144444	1454544	0.70
921600	923077	0.16
460800	461538	0.16
230400	230796	0.17
115200	115385	0.16
57600	57692	0.16
38400	38400	0.00
28800	28846	0.16
19200	19200	0.00
14400	14423	0.16
9600	9600	0.00

 Table 1: Example of Common Baud Rates

SPI CLK

SPI-MOSI

NFC_SPI_INT



NFC UTX

Pull low

6.2 NFC Host Interfaces (ISM43341 only)

The ISM43341 supports UART, I²C-compatible BSC, and SPI for the host interface physical transport layer. The host interface type is selected upon power-up boot, depending upon the state of the NFC_SPI_INT pin.

- NFC SPI INT pulled low The UART interface will be selected
- NFC SPI INT pulled high The I²C-compatible BSC slave interface will be selected
- NFC_SPI_INT floating The SPI interface will be selected. •

I2C_SDA

Pull high

After boot, the NFC_SPI_INT signal will function as the SPI interrupt output. During powerup book, the external host must leave this pin floating, as in the case of the tri-state or input pin. The external host must also ignore interrupts from this signal for a period of 10 milliseconds after boot-up.

UART BSC SPI NFC_CTS I2C_REQ SPI CS NFC_RTS I2C_SCL SPI MISO NFC URX

The NFC host interface pins are multiplexed onto shared signals as defined in Table 2.

Table 2: NFC Host Interface Multiplexing

7 ELECTRICAL SPECIFICATIONS

7.1 Absolute Maximum Ratings

Caution! The absolute maximum ratings in Table 28 indicate levels where permanent damage to the device can occur, even if these limits are exceeded for only a brief duration. Functional operation is not guaranteed under these conditions. Operation at absolute maximum conditions for extended periods can adversely affect long-term reliability of the device.

Rating	Symbol	Value	Unit
DC supply for VBAT and PA driver supply	VBAT	-0.5 to +6.0	V
DC supply voltage for digital I/O	VIO	-0.5 to 3.9	V

Table 3: Absolute Maximum Ratings



7.2 Environmental Ratings

Characteristic	Value	Units	Conditions/Comments
Ambient Temperature (Ta)	-30 to +85	°C	* Functional operation
Storage Temperature	-40 to +125	°C	-
	Less than 60	%	<u>Storage</u>
Relative Humidity	Less than 85	%	Operation

 Table 4: Environmental Ratings

7.3 Recommended Operating Conditions and DC Characteristics

<u>Caution!</u> Functional operation is not guaranteed outside of the limits shown in Table 31 and operation outside these limits for extended periods can adversely affect long-term reliability of this devices.

Parameter	Symbol	Min	Typical	Max	Unit
DC supply Voltage for VBAT	VBAT	3.0	3.3	4.8	V
DC supply voltage for digital I/O	VIO	1.8	3.3	3.6	V

Table 5: Recommended Operating Conditions and DC Characteristics

- a. The ISM43341 is functional across this range of voltages. Optimal RF performance specified in the data sheet, however, is guaranteed only for 3.0V >VBAT >4.8V.
- b. The maximum continuous voltage is 4.8V. Voltages up to 5.5V for up to 10 seconds, cumulative duration, over the lifetime of the device are allowed. Voltages as high as 5.0V for up to 250 seconds, cumulative duration, over the lifetime of the device are allowed.
- c. Programmable 2 mA to 16 mA drive strength. Default is 10 mA

8 RF SPECIFICATIONS

8.1 Bluetooth RF Specifications

Note: Values in this datasheet are design goals and are subject to change based on the result of device characterization.



Unless otherwise stated, limit values apply for the conditions specified in Tabel 29: "Environmental Ratings" on page 117 and table 31: "Recommended Operating Conditions and DC Characteristics" on page 118. Typical values apply for the following conditions:

- VBAT = 3.6V
- Ambient temperature +25°C

Parameter	Conditions	Min	Typical	Max	Unit
Note: The specifications in this tal specified:	ble are measured at t	he Chip port	t output unle	ess other	wise
General					
Frequency Range	-	2402	- /	2480	MHz
RX sensitivity	GFSK, 0.1% BER, 1 Mbps	-	-93.5	-	dBm
	π/4-DQPSK, 0.01% BER, 2 Mbps	- /	-95.5	-	dBm
	8-DPSK, 0.01% BER, 3 Mbps	/-	-89.5	-	dBm
Input IP3	-	-16	-	-	dBm
Maximum input at antenna	- /	-	-	-20	dBm

 Table 6: Bluetooth Receiver RF Specifications

Parameter	Conditions	Min	Typical	Max	Unit
General					
Frequency Range		2402	-	2480	MHz
Basic rate (GFSK) Tx power at Bluetooth	-	10.0	12.0	-	dBm
QPSK Tx Power at Bluetooth		7.0	9.0	-	dBm
8PSK Tx Power at Bluetooth		7.0	9.0	-	dBm
Power control step		2	4	6	dB

Table 7: Bluetooth Transmitter RF Specifications

8.2 WLAN RF Specifications



The ISM4443X includes an integrated dual-band direct conversion radio that supports either the 2.4 GHz band or the 5 GHz band. The ISM4443X does not provide simultaneous 2.4 GHz and 5 GHz operation. This section describes the RF characteristics of the 2.4 GHz and 5 GHz portions of the radio.

Note: Values in the data sheet are design goals and are subject to change based on the results of device characterization.

Unless otherwise stated, limit values apply for the condition specified in Table 29: "Environmental Ratings" on page 117 and Table 31: "Recommended Operating Conditions and DC Characteristics" on page 118. Typical values apply for the following conditions:

- VBAT = 3.6V
- Ambient temperature +25°C

2.4 GHz Band General RF Specifications

Item	Conditions	Min	Typical	Max	Unit
Tx/Rx switch time	Including TX ramp down	- /	-	5	μs
Rx/Tx switch time	Including TX ramp up	<u>/</u>	-	2	μs
Power-up and power- down ramp time	DSSS/CCK Modulations	-	-	<2	μs

 Table 8: 2.4 GHz Band General RF Specifications

WLAN 2.4 GHz Receiver Performance Specification

Parameter	Condition/Notes	Min	Typical	Max	Unit
Frequency Range	-	2400	-	2500	MHz
	1 Mbps DSSS	-	-97.9	-	dBm
RX sensitivity (8% PER for 1024	2 Mbps DSSS	-	-96.9	-	dBm
octet PSDU) ^a	5.5 Mbps DSSS	-	-92.5	-	dBm
	11 Mbps DSSS	-	-90.7	-	dBm
	6 Mbps OFDM	-	-92.7	-	dBm
	9 Mbps OFDM	-	-91.4	-	dBm
	12 Mbps OFDM	-	-89	-	dBm
RX sensitivity (10% PER for 1024	18 Mbps OFDM	-	-87.4	-	dBm
octet PSDU) ^a	24 Mbps OFDM	-	-84.4	-	dBm
	36 Mbps OFDM	-	-81.7	-	dBm
	48 Mbps OFDM	-	-78.3	-	dBm
	54 Mbps OFDM	-	-77.1	-	dBm
RX sensitivity (10% PER for 4096	20 MHz channel spa	acing for all	MCS rates	(GF)	



Embedding Connectivity Everywhere			ISM4334x	Product Sp	ecification	
octet PSDU) ^a , ^b Defined for	MCS0	-	-92.6	-	dBm	
default perameters: GF, 800 ns	MCS 1	-	-89.6	-	dBm	
GI, and non-STBC.	MCS 2	-	-87.3	-	dBm	
	MCS 3	-	-84.7	-	dBm	
	MCS 4	-	-82	-	dBm	
	MCS 5	-	-78.4	-	dBm	
	MCS 6	-	-76.9	-	dBm	
	MCS 7	-	-75	-	dBm	
	40 MHz channel spa	acing for all		(GF)		
	MCS0	-	-91	-	dBm	
DX consitivity (10% DED for 1006	MCS 1	-	-87.5	-	dBm	
RX sensitivity (10% PER for 4096 octet PSDU) ^a , ^b Defined for	MCS 2	-	-85.5	- /	dBm	
default perameters: GF, 800 ns	MCS 3	-	-83	_	dBm	
GI, and non-STBC.	MCS 4	-	-80		dBm	
	MCS 5	-	75	-	dBm	
	MCS 6	-	-73.5	-	dBm	
	MCS 7	-	-72	-	dBm	
	20 MHz channel spacing for all MCS rates (Mixed mode)					
	MCS0	- /	-91	-	dBm	
RX sensitivity (10% PER for 4096	MCS 1	- /	-87.9	-	dBm	
octet PSDU) ^a , ^c Defined for	MCS 2	/-	-85.5	-	dBm	
default perameters: Mixed mode-	MCS 3		-82.8	-	dBm	
800n ns GI, and non-STBC.	MCS 4	-	-79.9	-	dBm	
	MCS 5	-	-76.2	-	dBm	
	MCS 6	-	-74.6	-	dBm	
	MCS 7	-	-72.6	-	dBm	
	40 MHz channel spa	acing for all		(Mixed m	· · · · ·	
	MCS0	-	-89.0	-	dBm	
RX sensitivity (10% PER for 4096	MCS 1	-	-85.4	-	dBm	
octet PSDU) ^a , ^b Defined for	MCS 2	-	-83.2	-	dBm	
default perameters: GF, 800 ns GI, and non-STBC.	MCS 3	-	-80.6	-	dBm	
	MCS 4	-	-77.4	-	dBm	
	MCS 5	-	-72.3	-	dBm	
	MCS 6	-	-70.6	-	dBm	
	MCS 7	-	-69.0	-	dBm	

 Table 9: WLAN 2.4 GHz Receiver Performance Specifications

WLAN 5 GHz Receiver Performance Specifications

Note: The specifications in Table 40 are measured at the chip port input, unless otherwise specified

Parameter	Condition/Notes	Min	Typical	Max	Unit
Frequency Range	-	4900	-	5845	MHz
RX sensitivity (10% PER for 1000	6 Mbps OFDM	-	-91.2	-	dBm
octet PSDU) ^a	9 Mbps OFDM	-	-89.9	-	dBm



Embedding Connectivity Everywhere			ISM4334x Pr	oduct Spec	cification		
	12 Mbps OFDM	-	-87.5	-	dBm		
	18 Mbps OFDM	-	-85.9	-	dBm		
	24 Mbps OFDM	-	-82.9	-	dBm		
	36 Mbps OFDM	-	-80.2	-	dBm		
	48 Mbps OFDM	-	-76.8	-	dBm		
	54 Mbps OFDM	-	-75.6	-	dBm		
	20 MHz channel spa	20 MHz channel spacing for all MCS rates (GF)					
	MCS0	-	-91.1	-	dBm		
BX consitivity (10% DED for 4006	MCS 1	-	-88.1	-	dBm		
RX sensitivity (10% PER for 4096 octet PSDU) ^a	MCS 2	-	-85.8	-	dBm		
Defined for default perameters: GF,	MCS 3	-	-83.2	-	dBm		
800 ns GI, and non-STBC.	MCS 4	-	-80.5	_	dBm		
	MCS 5	-	76.9	/ -	dBm		
	MCS 6	-	75.4	-	dBm		
	MCS 7	-	-73.5	-	dBm		
	40 MHz channel spa	cing for all	MCS rates	<u>(GF)</u>			
	MCS0	-	-89.5	-	dBm		
RX sensitivity (10% PER for 4096	MCS 1	- /	-86	-	dBm		
octet PSDU) ^a	MCS 2	- /	-84	-	dBm		
Defined for default perameters: GF, 800 ns GI, and non-STBC.	MCS 3	_	-81.5	-	dBm		
	MCS 4	- /	-78.5	-	dBm		
	MCS 5	-	-73.5	-	dBm		
	MCS 6	-	-72	-	dBm		
	MCS 7	-	-70.5	-	dBm		

 Table 10: WLAN 5 GHz Receiver Performance Specifications

8.3 Environmental Specifications

Item	Description
Operating temperature range	-40 deg. C to +85 deg. C
Storage temperature range	-40 deg. C to +85 deg. C
Humidity	95% max non-condensing

Note 1: The ISM4443X supports a functional operating range of -40°C to +85°C. However the optimal RF performance specified in this data sheet is only guaranteed for temperatures from -10°C to +65°C



9 PIN OUT AND DESCRIPTIONS

9.1 Module Pin-Out (1 of 2)







9.2 Module Pin-Out (2 of 2)







9.3 Recommended PCB Footprint (Bottom View)





9.4 Recommended PCB Footprint (Top View)





9.5 Detailed Pin Description

Pin No.	Name	ТҮРЕ	Description	
1	RFIN_5G	RF in	RF IN 5G	
2	Ground	G	GRD	
3	Ground	G	GRD	
4	5 GHZ & 2.4 G RF in	RF in		
5	Ground	G	GRD	
6	2.4 G RF in	RF in	RF IN 2G	
7	Ground	G		
8	WRF_GPIO_OUT	G	GPIO_OUT	
9	RF_SWO	0	Ext. RF Switch Enable -NC	
10	RF_SW3	0	Ext. RF Switch Enable -NC	
11	RF_SW4	0	Ext. RF Switch Enable -NC	
12	BT_HOST_WAKE	0	BT_Host_Wake to Host Active High	
13	32 Khz sleep clk			
14	NFC_REG_PU	I	NFC Regulator Power Up Active High	
15	BT_12S_DO		BT_I2S DO	
			/	
16	BT_125_CLK		BT_I2S_CLK	
17	BT_12S_WS		BT_I2S_WS	
18	BT_PCM_SYNC		BT PCM Sync	
19	BT_PCM_CLK		BT PCM Clock	
20	BT_PCM_OUT		BT_PCM _Out	
21	BT_PCM_IN		BT_PCM In	
22	BT_DEV_WAKE	1	BT Dev Wake up from Host Active High	
23	Vio	V	I/O Supply Voltage (1.8-3.3V)	
24	BT_UART_CTS_L	I	BT_UART_CTS_N	
25	BT_UART_RTS_L	0	BT_UART_RTS_N	
26	BT_UART_TXD	I/O	BT_UART_TXD	
27	BT_UART_RXD	I/O	BT_UART_RXD	
28	*NFC_VDDSWPIN_0	1	NFC single wire protocol and power - UICC	
29	*NFC_VDDSWP_0	0	NFC single wire protocol and power	
30	*NFC_RTS	0	NFC UART Request to Send	
31	*NFC_CTS	Ι	NFC UART Clear-to-Send	
32	*NFC_TX2	RF	NFC antenna TX/RX Pin 2	
33	*NFC_TX1	RF	NFC antenna TX/RX Pin 1	
34	*NFC_SDA	I/O	BSC data for EEPROM	
35	*NFC_SCL	0	BSC clock for EEPROM	
36	*NFC_SPI_INT	I/O	NFC Host Interface/Select SPI interrupt	



ISM4334x Product Specification

*NFC_GPIO1	1/0	NFC GPIO	
GND	G	Gnd	
SDIO_CLK	I	SDIO clk	
SDIO_CMD	I/O	SDIO command Lin or data input	
SDIO_DATA_0	I/O	SDIO data	
SDIO_DATA_1	I/O	SDIO 1	
SDIO_DATA_2	I/O	SDIO 2	
SDIO_DATA_3	I/O	SDIO 3	
*NFC_URX	I	NFC UART RX	
*NFC_UTX	0	NFC UART TX	
GND	G	Ground	
*NFC_SWPIO_0	I/O	NFC single wire protocol and power	
JTAG_SEL		JTAG Select (High to select JTAG)	
WL_REG_ON	1	Wireless LAN Power up (Active high)	
BT_REG_ON	1	Power up Bluetooth (Active High)	
GPIO 0	0	GPIO	
		GPIO	
		GPIO	
	•	3.3v	
		3.3v	
		Ground	
		Ground	
		Ground	
	G	Ground	
	G	Ground	
/	G	Ground	
	0	Ground	
	G	Ground	
	GND SDIO_CLK SDIO_CMD SDIO_DATA_0 SDIO_DATA_1 SDIO_DATA_2 SDIO_DATA_3 *NFC_URX *NFC_URX *NFC_UTX GND *NFC_SWPIO_0 JTAG_SEL WL_REG_ON	GND G SDIO_CLK I SDIO_CMD I/O SDIO_DATA_0 I/O SDIO_DATA_1 I/O SDIO_DATA_2 I/O SDIO_DATA_3 I/O *NFC_URX I *NFC_SWPIO_0 I/O JTAG_SEL I WL_REG_ON I BT_REG_ON I BT_REG_ON I GPIO_0 O GPIO_1 I/O GPIO_6 I/O GPIO_6 I/O GO G GO G	



70		G	Ground
71	WL_GPIO2		WL_GPIO2
72	WL_GPIO3		WL_GPIO3
73	WL_GPIO4		WL_GPIO4
74	WL_GPIO5		WL_GPIO5
75	WL_GPIO_12		WL_GPIO_12
76		G	Ground
77		G	Ground

Note: All NFC pins labelled with (*) are only available for ISM43341, and for ISM43340 these pins should be left floating.

10 Product Compliance Considerations

RoHS: Restriction of Hazardous Substances (RoHS) directive has come into force since 1st July 2006 all electronic products sold in the EU must be free of hazardous materials, such as lead. Inventek is fully committed to being one of the first to introduce lead-free products while maintaining backwards compatibility and focusing on a continuously high level of product and manufacturing quality.

EMI/EMC: The Inventek module design embeds EMI/EMC suppression features and accommodations to allow for higher operational reliability in noisier (RF) environments and easier integration compliance in host (OEM) applications.

FCC/CE: The module will be in compliance test for FCC/CE



11 Reflow Profile

- Reference the IPC/JEDEC standard.
- Peak Temperature: <250°C
- Number of Times: ≤2 times





12 Packaging Information

12.1 MSL Level / Storage Condition

This MOISTU Do not ope 1. Calculated she < 90% relative	LEVEL 4 4 4 4 4 4 4 4 4 4 4 4 4
solder or other	
성 집에 가면서 이렇게 것 같아. 여러 집에 가지 않는다.	e bake, before mounting, if: icator Card is>10%when read at 23±5℃ met
5. If baking is req at 125±5′C	uired, devices may be baked for 24 hours
temperature or	containers cannot be subjected to high shorter bake times are desired, JEDEC J-STD-033 for bake procedure
Bag Seal Dat <u>e:</u>	See-SEAL DATELABEL
Note:Level and body	temperature defined by IPC/JEDED J-STD-020



12.2 Device baking requirements prior to assembly

Boards must be baked prior to rework or assembly to avoid damaging moisture sensitive components during localized reflow. The default bake cycles is 24 hours at 125C. Maintaining proper control of moisture uptake in components is critical. Before opening the shipping bag and attempting solder reflow, you should maintain a minimal out-of-bag time and ensure the highest possible package reliability for the final product.

13 REVISION CONTROL

Document : ISM4443X	Wi-Fi SIP module
External Release	DOC-DS-20023

Date	Author	Revision	Comment
1/15/2015	KMT	1.0	Preliminary
12/17/2015	KMT	1.1	Released
1/12/2016	KMT	1.2	Pin list Update
3/22/2016	KMT	3.2	Pin Description, added
			Power Consumption and P/N
			,

14 CONTACT INFORMATION

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